

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Gehrke et al.)	
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Serial No.: 10/763,588)	Confirmation No.: 7739
)	
Filed: August 4, 2003)	
)	
Group Art Unit: 2822)	
Examiner: Guerrero)	
)	
Title: Pendoeptaxial Methods of Fabricating)	
Gallium Nitride Semiconductor Layers on)	
Sapphire Substrates, and Gallium Nitride)	
Semiconductor Structures Fabricated)	
Thereby)	
)	

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE UNDER 37 C.F.R. § 1.111

Sir:

This paper is being filed in response to the Office Action mailed May 5, 2006, having a reply due date of August 5, 2006. The Applicants hereby petition the Commissioner for Patents to extend the time for response by one (1) month to at least September 5, 2006. The appropriate fee for a Petition for Extension of Time is enclosed. Reconsideration of the application is respectfully requested in light of this response.

Amendments to the Specification There are no amendments to the specification.

Amendments to the Claims begin on page 2 of this paper.

Remarks/Arguments begin on page 8 of this paper.